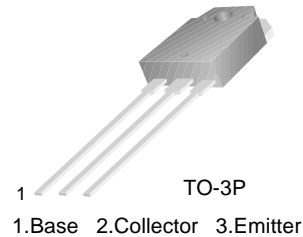


KSC2751

KSC2751

High Speed
High Current Switching Industrial Use



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	15	A
I_{CP}	*Collector Current (Pulse)	30	A
I_B	Base Current (DC)	7.5	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	120	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 55 ~ 150	$^\circ\text{C}$

* $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 10\%$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 10\text{A}$, $I_{B1} = 2\text{A}$, $L = 50\mu\text{H}$	400			V
$V_{CEX(sus)1}$	Collector-Emitter Sustaining Voltage	$I_C = 10\text{A}$, $I_{B1} = -I_{B2} = 2\text{A}$ $T_C = 125^\circ\text{C}$, $L = 180\mu\text{H}$, Clamped	450			V
$V_{CEX(sus)2}$	Collector-Emitter Sustaining Voltage	$I_C = 20\text{A}$, $I_{B1} = 4\text{A}$, $-I_{B2} = 2\text{A}$ $T_C = 125^\circ\text{C}$, $L = 180\mu\text{H}$, Clamped	400			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 400\text{V}$, $I_E = 0$			100	μA
I_{CER}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $R_{BE} = 50\Omega$ @ $T_C = 125^\circ\text{C}$			2	mA
I_{CEX1}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $V_{BE(off)} = -1.5\text{V}$			100	μA
I_{CEX2}	Collector Cut-off Current	$V_{CE} = 400\text{V}$, $V_{BE(off)} = -1.5\text{V}$ @ $T_C = 125^\circ\text{C}$			1	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}$, $I_C = 0$			10	μA
h_{FE1} h_{FE2} h_{FE3}	* DC Current Gain	$V_{CE} = 5\text{V}$, $I_C = 2\text{A}$ $V_{CE} = 5\text{V}$, $I_C = 5\text{A}$ $V_{CE} = 5\text{V}$, $I_C = 10\text{A}$	15 10 7	35	80	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 10\text{A}$, $I_B = 2\text{A}$		0.3	1	V
$V_{BE(sat)}$	* Base Emitter ON Voltage	$I_C = 10\text{A}$, $I_B = 2\text{A}$		1	1.5	V
t_{ON}	Turn ON Time	$V_{CC} = 150\text{V}$, $I_C = 10\text{A}$			1	μs
t_{STG}	Storage Time	$I_{B1} = -I_{B2} = 2\text{A}$			2.5	μs
t_F	Fall Time	$R_L = 15\Omega$			0.7	μs

* Pulse Test: $PW \leq 350\mu\text{s}$, Duty Cycle $\leq 2\%$ Pulsed

h_{FE} Classification

Classification	N	R	O	Y
h_{FE1}	15 ~ 30	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

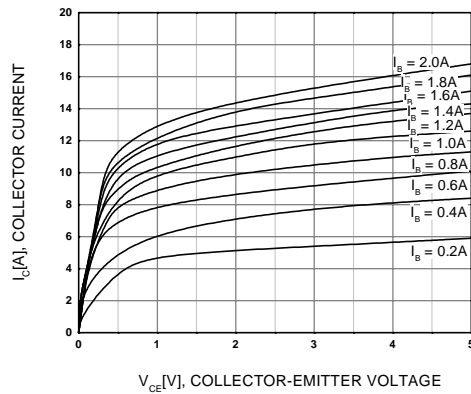


Figure 1. Static Characteristic

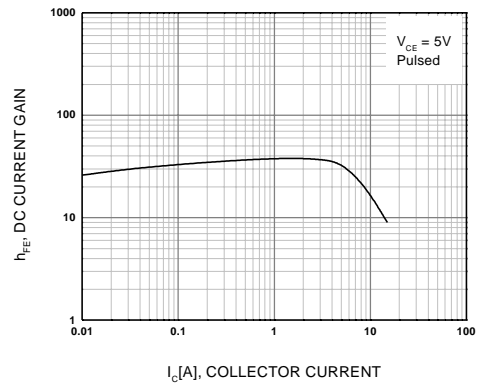


Figure 2. DC current Gain

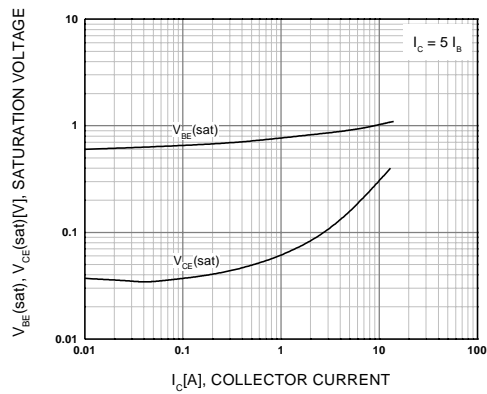


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

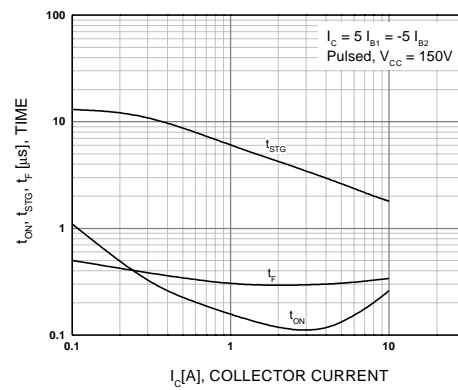


Figure 4. Switching Time

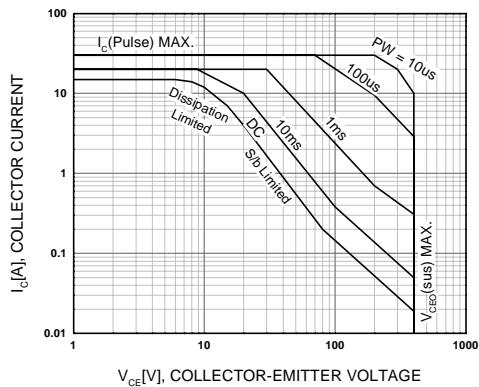


Figure 5. Safe Operating Area

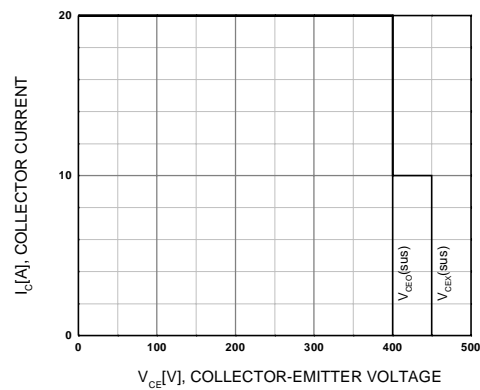


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

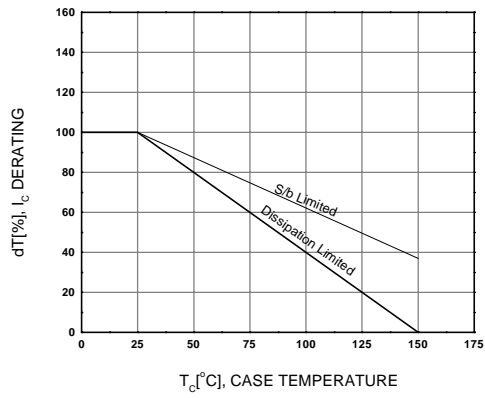


Figure 7. Derating Curve of Safe Operating Area

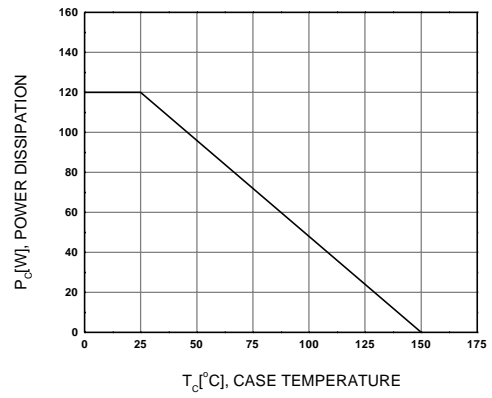
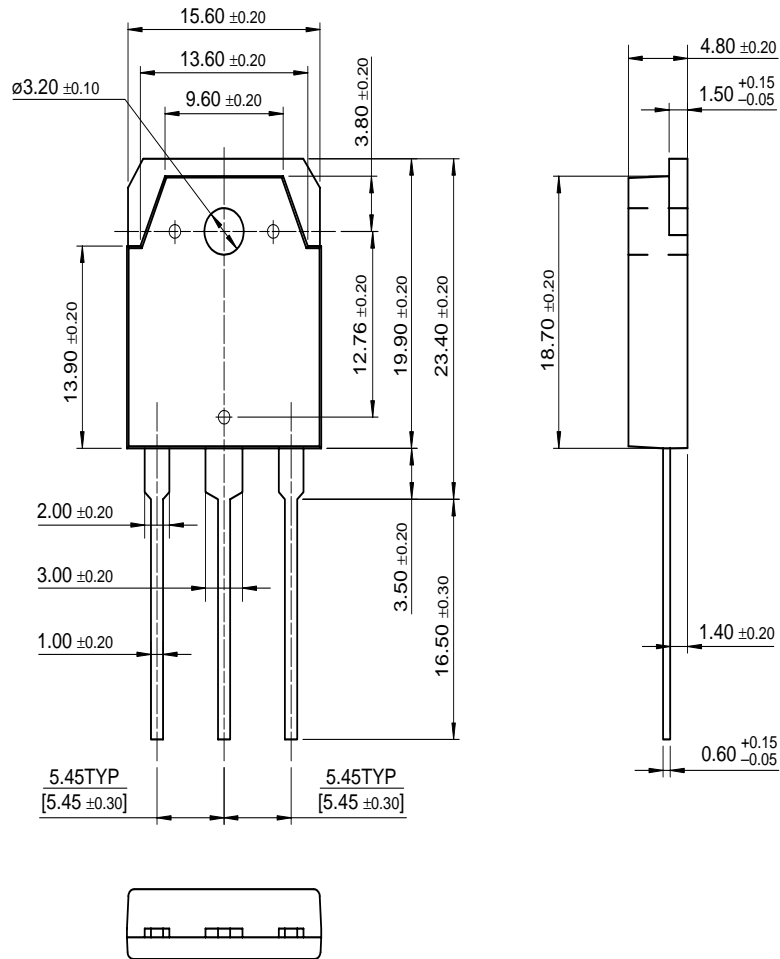


Figure 8. Power Derating

Package Dimensions

TO-3P



Dimensions in Millimeters

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FACT™	QFET™	
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